THE UNITED STATES PATENT AND TRADEWARK OFFICE.

REVOCATION AND NEW POWER OF ATTORNEY AND CHANGE OF CORRESPONDENCE ADDRESS

I, Bradley D. Kohn, Authorized Officer of Solaicx, the Assignee of the entire right, title, and interest in the U.S. Patent Application(s) and/or Patent(s) identified on the attached Schedule A, hereby revoke all previous powers of attorney or authorizations of agent given and do hereby appoint the attorneys or agents associated with the following Customer Number, with full power of substitution and revocation, to prosecute and transact all business in the Patent and Trademark Office connected therewith for the U.S. Patent Application(s) and/or Patent(s) listed in the attached Schedule A:

Customer Number: 76681

Please direct all correspondence in connection with said U.S. Patent Application(s) and/or Patent(s) to:

Customer Number: 76681

Respectfully submitted.

Date: _ 9/12/11

Bredh D. Kil-

General Counsel of MEMC Electronic Materials, Inc.

Authorized Officer of Solaicx

THE UNITED STATES PATENT AND TRADEMARK OFFICE

STATEMENT UNDER 37 CFR 3.73(b)

Solaicx, a California Corporation, pursuant to 37 CFR 3.73(b), hereby states that it is the Assignee of the entire right, title, and interest in U.S. Patent Application(s) and/or Patent(s) on the attached Schedule A.

The entire rights, title, and interest in the aforementioned Patent Application(s) and/or Patent(s) were conveyed to Sodiacx via Assignment(s) recorded with the United States Patent and Trademark Office at the Reel/Frame Numbers on the attached Schedule A.

The undersigned, Bradley D. Kohn, Autorized Officer, has full authorization to act on behalf of Assignee Soliacs.

Respectfully submitted,

Date: 9/12/11

Bradley D. Kohn

General Counsel of MEMC Electronic Materials, Inc. Authorized Officer of Solaicx

SCHEDULE A

File Ref.	TITLE	US Serial No. & Filing Date	Publication No & Publication Date	Patent No. & Issue Date	Reel/Frame
28744-3642 110033.1	System for Continuous Growing of Monocrystalline Silicon	10/789,638 2/27/2004	2005/0092236 05/05/2005	7,635,414	015033/0937
28744-3644 110033.3	System for Continuous Growing of Monocrystalline Silicon	10/525,824	2008/0134958 06/12/2008		021694/0069
28744-3645 110033.4	System for Continuous Growing of Monocrystalline Silicon	12/653,910 12/17/2009	2010/0162946		Continuation of 10/789,638 Recorded at 015033/0937
28744-3659 110035.2	High Temperature Heating Element for Preventing Contamination of a Workpiece	11/893,254 8/14/2007	US 2008/0041836 A1 02/21/2008		021555/0081
28744-3666 110039.1	Formation of a Silicon Sheet by Cold Surface Casting	10/918,681 08/12/2004	Not published	7,294,197 11/13/2007	021547/0571
28744-3668 110040.1 SOLX 9	Weir Design Providing Optimal Purge Gas Flow, Melt Control, And Temperature Stabilization For Improved Single Crystal Growth In A Continuous CZ Procese	12/075,513	Not published		026815/0667
28744-3671 110042.1 SOLX 11	Method and Apparatus for Controlling Melt Temperature in a Czochralski Grower	12/315,681	Not published		026815/0586
28744-3674 110044.1 SOLX 13	Crucible Weight Measurement System for Controlling Feedstock Introduction in Czochralski Crystal Growth	12/315,452	Not published		026815/0432